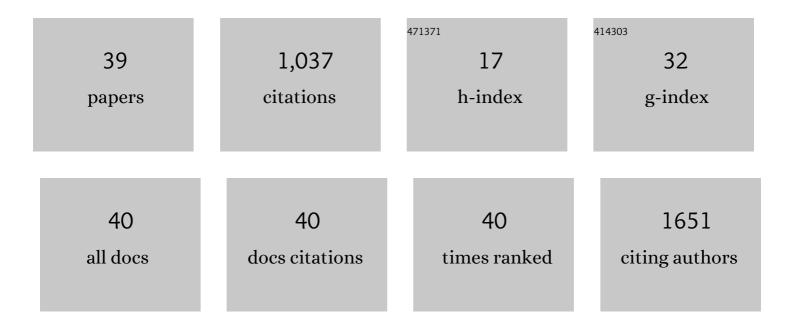
Sujitra J Pookpanratana

List of Publications by Year in descending order

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#	Article	IF	CITATIONS
1	Organic single crystals of charge-transfer complexes: model systems for the study of donor/acceptor interactions. Materials Horizons, 2022, 9, 271-280.	6.4	10
2	Imaging and measuring the electronic properties of epitaxial graphene with a photoemission electron microscope. Journal of Applied Physics, 2022, 131, .	1.1	3
3	Commissioning and Calibration of a Photoemission Electron Microscope. Microscopy and Microanalysis, 2021, 27, 634-634.	0.2	Ο
4	Alternatives to aluminum gates for silicon quantum devices: Defects and strain. Journal of Applied Physics, 2021, 130, 115102.	1.1	3
5	Nonvolatile memory based on redox-active ruthenium molecular monolayers. Applied Physics Letters, 2019, 115, 162102.	1.5	6
6	Contrasting Transport and Electrostatic Properties of Selectively Fluorinated Alkanethiol Monolayers with Embedded Dipoles. Journal of Physical Chemistry C, 2018, 122, 4881-4890.	1.5	13
7	Contact and Noncontact Measurement of Electronic Transport in Individual 2D SnS Colloidal Semiconductor Nanocrystals. ACS Nano, 2018, 12, 10045-10060.	7.3	19
8	Electronic properties and structure of single crystal perylene. Organic Electronics, 2018, 61, 157-163.	1.4	15
9	Reply to Comment on Polymorphism in the 1:1 Chargeâ€Transfer Complex DBTTFâ€TCNQ and Its Effects on Optical and Electronic Properties. Advanced Electronic Materials, 2017, 3, 1600521.	2.6	2
10	Organic Electronics: The Influence of Isomer Purity on Trap States and Performance of Organic Thinâ€Film Transistors (Adv. Electron. Mater. 1/2017). Advanced Electronic Materials, 2017, 3, .	2.6	0
11	Zn–Se–Cd–S Interlayer Formation at the CdS/Cu ₂ ZnSnSe ₄ Thin-Film Solar Cell Interface. ACS Energy Letters, 2017, 2, 1632-1640.	8.8	31
12	The Influence of Isomer Purity on Trap States and Performance of Organic Thinâ€Film Transistors. Advanced Electronic Materials, 2017, 3, 1600294.	2.6	37
13	Chemical-doping-driven crossover from graphene to "ordinary metal―in epitaxial graphene grown on SiC. Nanoscale, 2017, 9, 11537-11544.	2.8	16
14	(Invited) Interface Engineering for Nanoelectronics. ECS Transactions, 2017, 80, 119-131.	0.3	1
15	Site- and Symmetry-Resolved Resonant X-ray Emission Study of a Highly Ordered PTCDA Thin Film. Journal of Physical Chemistry C, 2016, 120, 8607-8615.	1.5	1
16	Polymorphism in the 1:1 Chargeâ€Transfer Complex DBTTF–TCNQ and Its Effects on Optical and Electronic Properties. Advanced Electronic Materials, 2016, 2, 1600203.	2.6	83
17	Non-volatile memory devices with redox-active diruthenium molecular compound. Journal of Physics Condensed Matter, 2016, 28, 094009.	0.7	23
18	Modifying Spin Injection Characteristics in the Co/Alq ₃ System by Using a Molecular Self-Assembled Monolayer. Journal of Physical Chemistry C, 2015, 119, 12949-12955.	1.5	10

#	Article	IF	CITATIONS
19	Redox-Active Molecular Nanowire Flash Memory for High-Endurance and High-Density Nonvolatile Memory Applications. ACS Applied Materials & Interfaces, 2015, 7, 27306-27313.	4.0	59
20	Self-Assembled Monolayers Impact Cobalt Interfacial Structure in Nanoelectronic Junctions. Journal of Physical Chemistry C, 2015, 119, 6687-6695.	1.5	16
21	Attachment of a Diruthenium Compound to Au and SiO ₂ /Si Surfaces by "Click―Chemistry. Langmuir, 2014, 30, 10280-10289.	1.6	17
22	Interface Engineering To Control Magnetic Field Effects of Organic-Based Devices by Using a Molecular Self-Assembled Monolayer. ACS Nano, 2014, 8, 7192-7201.	7.3	19
23	Soft X-rays shedding light on thin-film solar cell surfaces and interfaces. Journal of Electron Spectroscopy and Related Phenomena, 2013, 190, 47-53.	0.8	7
24	Soft X-ray and electron spectroscopy to determine the electronic structure of materials for photoelectrochemical hydrogen production. Journal of Electron Spectroscopy and Related Phenomena, 2013, 190, 106-112.	0.8	9
25	Electrical and Physical Characterization of Bilayer Carboxylic Acid-Functionalized Molecular Layers. Langmuir, 2013, 29, 2083-2091.	1.6	12
26	Non-volatile memory with self-assembled ferrocene charge trapping layer. Applied Physics Letters, 2013, 103, .	1.5	19
27	Cu ₂ ZnSnS ₄ thin-film solar cell absorbers illuminated by soft x-rays. Journal of Materials Research, 2012, 27, 1097-1104.	1.2	14
28	Ultrafast Proton Dynamics in Aqueous Amino Acid Solutions Studied by Resonant Inelastic Soft X-ray Scattering. Journal of Physical Chemistry B, 2012, 116, 13757-13764.	1.2	37
29	Microstructure of vanadium-based contacts on n-type GaN. Journal Physics D: Applied Physics, 2012, 45, 105401.	1.3	5
30	Cliff-like conduction band offset and KCN-induced recombination barrier enhancement at the CdS/Cu2ZnSnS4 thin-film solar cell heterojunction. Applied Physics Letters, 2011, 99, .	1.5	181
31	Impact of KCN etching on the chemical and electronic surface structure of Cu2ZnSnS4 thin-film solar cell absorbers. Applied Physics Letters, 2011, 99, .	1.5	69
32	Native oxidation and Cu-poor surface structure of thin film Cu2ZnSnS4 solar cell absorbers. Applied Physics Letters, 2011, 99, .	1.5	48
33	The electrochemical reduction of PdCl42â^' and PdCl62â^' in polyaniline: Influence of Pd deposit morphology on methanol oxidation in alkaline solution. Electrochimica Acta, 2011, 56, 6060-6070.	2.6	18
34	Sulfur gradient-driven Se diffusion at the CdS/CuIn(S,Se)2 solar cell interface. Applied Physics Letters, 2010, 96, .	1.5	22
35	Nondestructive depth-resolved spectroscopic investigation of the heavily intermixed In2S3/Cu(In,Ga)Se2 interface. Applied Physics Letters, 2010, 96, 184101.	1.5	24
36	Effects of postdeposition treatments on surfaces of CdTe/CdS solar cells. Applied Physics Letters, 2010. 97. 172109.	1.5	22

#	Article	IF	CITATIONS
37	Solid and liquid spectroscopic analysis (SALSA)–a soft x-ray spectroscopy endstation with a novel flow-through liquid cell. Review of Scientific Instruments, 2009, 80, 123102.	0.6	77
38	Depth-resolved band gap in Cu(In,Ga)(S,Se)2 thin films. Applied Physics Letters, 2008, 93, .	1.5	72
39	Intermixing and chemical structure at the interface between n-GaN and V-based contacts. Applied Physics Letters, 2008, 93, .	1.5	14